

PJU4NA65 / PJD4NA65 / PJP4NA65 / PJF4NA65

650V N-Channel MOSFET

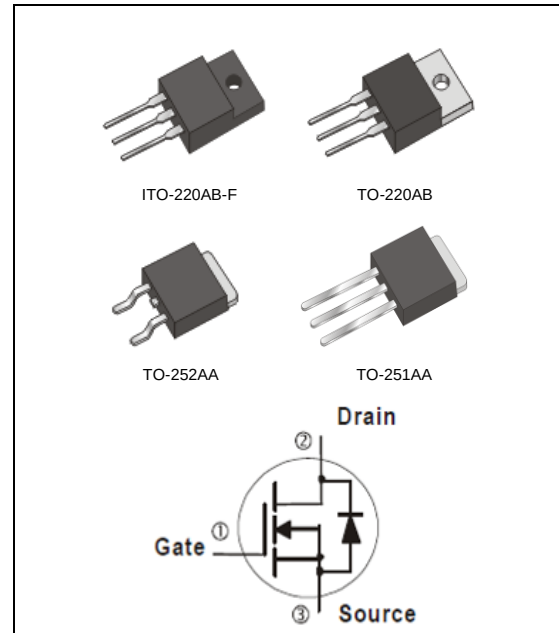
Voltage	650 V	Current	4 A
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Features

- $R_{DS(ON)}$, $V_{GS}@10V, I_D@2A < 2.7\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : TO-251AA, TO-252AA, TO-220AB, ITO-220AB-F Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-252AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-220AB Approx. Weight : 0.067 ounces, 2 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-220AB	ITO-220AB-F	TO-252AA	UNITS
Drain-Source Voltage		V_{DS}	650				V
Gate-Source Voltage		V_{GS}	± 30				V
Continuous Drain Current		I_D	4				A
Pulsed Drain Current		I_{DM}	16				A
Single Pulse Avalanche Energy ^(Note 1)		E_{AS}	202				mJ
Power Dissipation	$T_C=25^\circ\text{C}$	P_D	77	100	33	77	W
	Derate above 25°C		0.62	0.8	0.26	0.62	W/ $^\circ\text{C}$
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150				$^\circ\text{C}$
Typical Thermal resistance							
- Junction to Case		$R_{\theta JC}$	1.62	1.25	3.79	1.62	$^\circ\text{C/W}$
- Junction to Ambient		$R_{\theta JA}$	110	62.5	120	110	

- Limited only By Maximum Junction Temperature



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Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

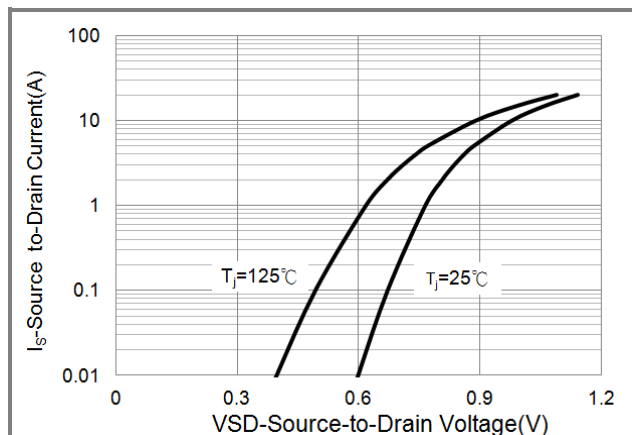
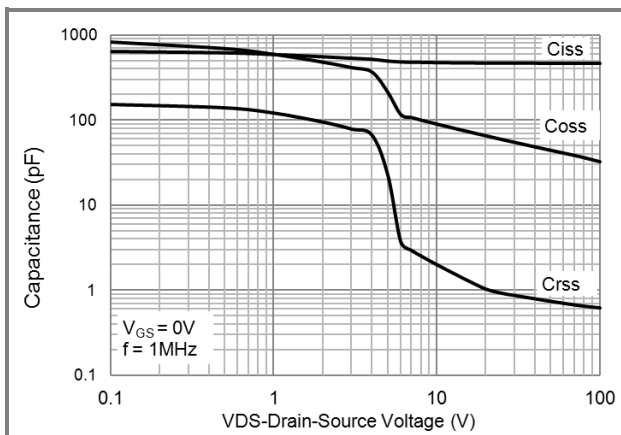
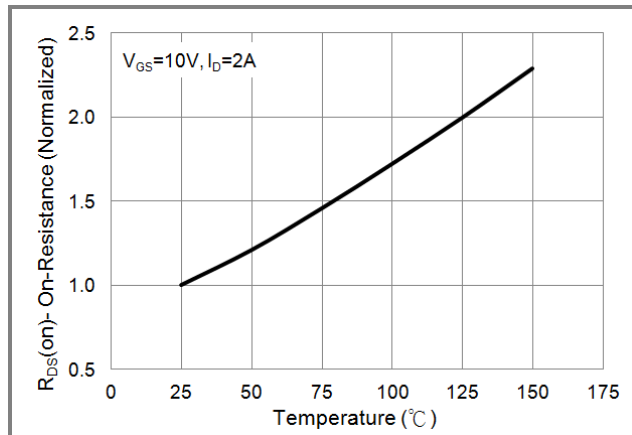
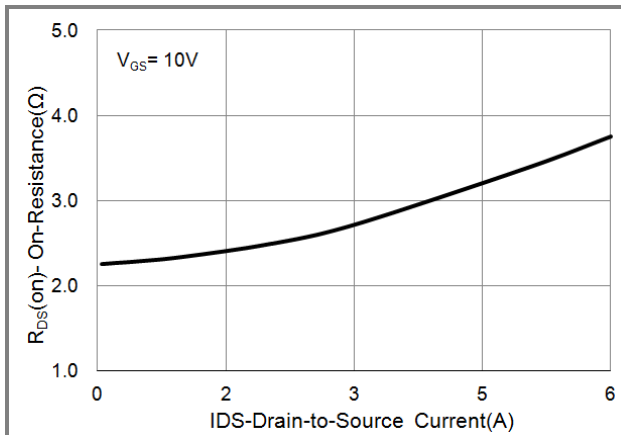
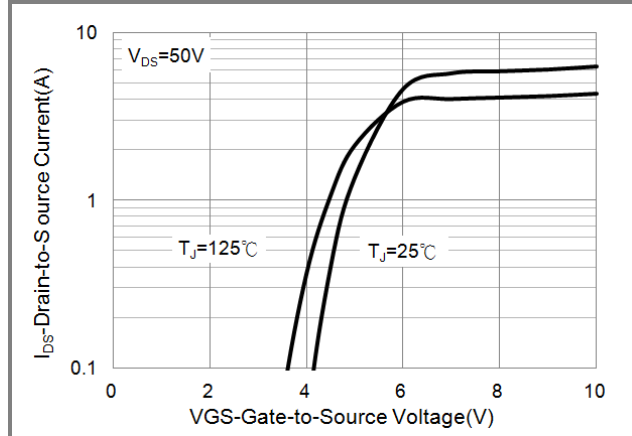
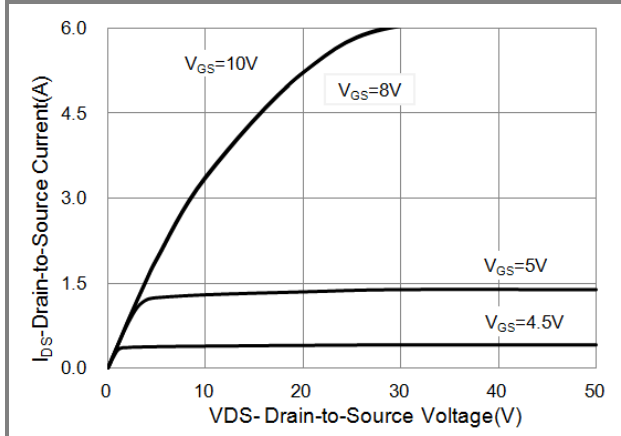
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	650	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	2	3.4	4	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =2A	-	2.44	2.7	Ω
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =650V, V _{GS} =0V	-	0.03	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±30V, V _{DS} =0V	-	±10	±100	nA
Diode Forward Voltage	V _{SD}	I _S =4A, V _{GS} =0V	-	0.87	1.4	V
Dynamic (Note 4)						
Total Gate Charge	Q _g	V _{DS} =520V, I _D =4A, V _{GS} =10V (Note 2,3)	-	11.4	-	nC
Gate-Source Charge	Q _{gs}		-	3	-	
Gate-Drain Charge	Q _{gd}		-	4.7	-	
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	463	-	pF
Output Capacitance	C _{oss}		-	60	-	
Reverse Transfer Capacitance	C _{rss}		-	1	-	
Turn-On Delay Time	td _(on)	V _{DD} =325V, I _D =4A, R _G =25Ω (Note 2,3)	-	9	-	ns
Turn-On Rise Time	t _r		-	23	-	
Turn-Off Delay Time	td _(off)		-	21	-	
Turn-Off Fall Time	t _f		-	23	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	4	A
Maximum Pulsed Drain-Source Diode Forward Current	I _{SM}	---	-	-	16	A
Reverse Recovery Time	trr	V _{GS} =0V, I _S =4A	-	266	-	ns
Reverse Recovery Charge	Qrr	di _F / dt=100A/us (Note 2)	-	2.24	-	uC

NOTES :

1. $L=30mH, I_{AS}=3.6A, V_{DD}=50V, R_G=25\Omega$, Starting $T_J=25^{\circ}\text{C}$
2. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
3. Essentially independent of operating temperature typical characteristics.
4. Guaranteed by design, not subject to production testing

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TYPICAL CHARACTERISTIC CURVES



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TYPICAL CHARACTERISTIC CURVES

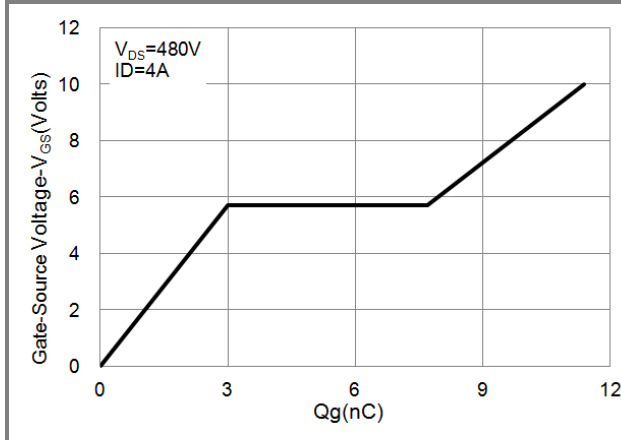


Fig.7 Gate Charge

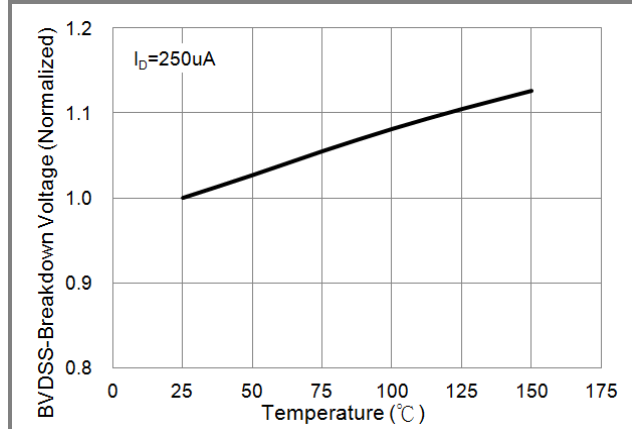


Fig.8 BV_{DS} vs. Junction Temperature

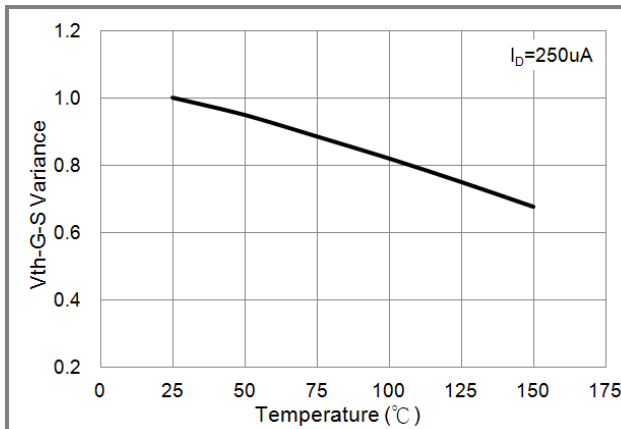


Fig.9 Threshold Voltage Variation with Temperature

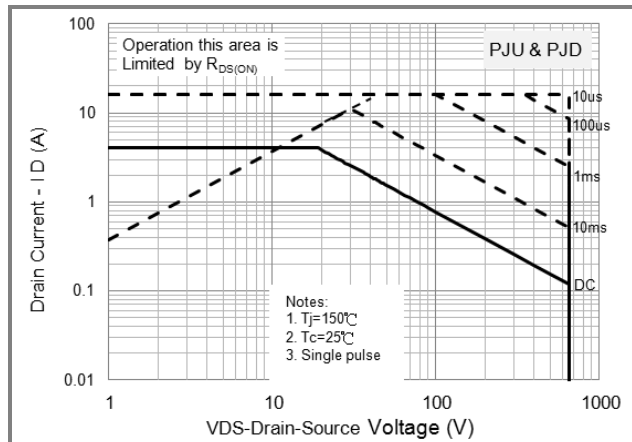


Fig.10 Maximum Safe Operating Area

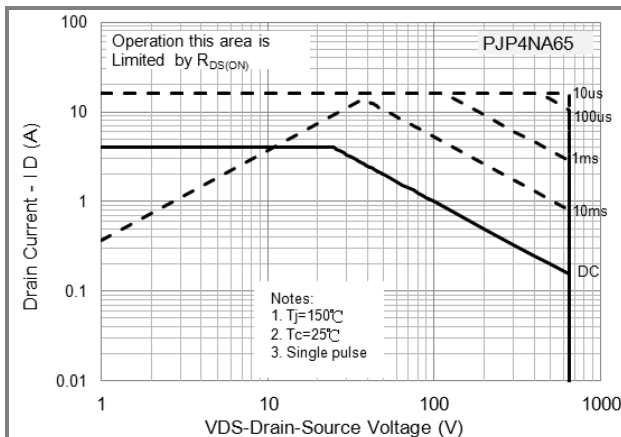


Fig.11 Maximum Safe Operating Area

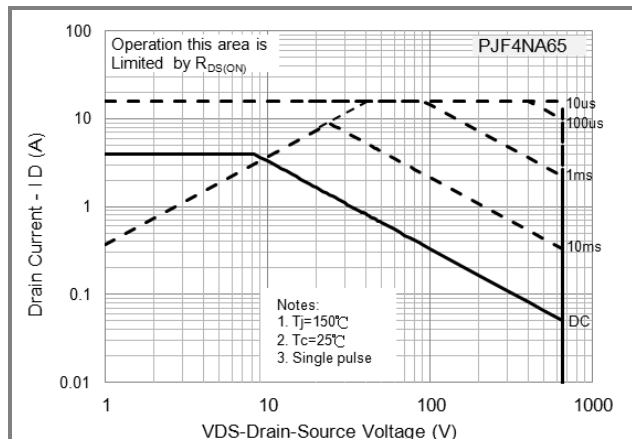


Fig.12 Maximum Safe Operating Area

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TYPICAL CHARACTERISTIC CURVES

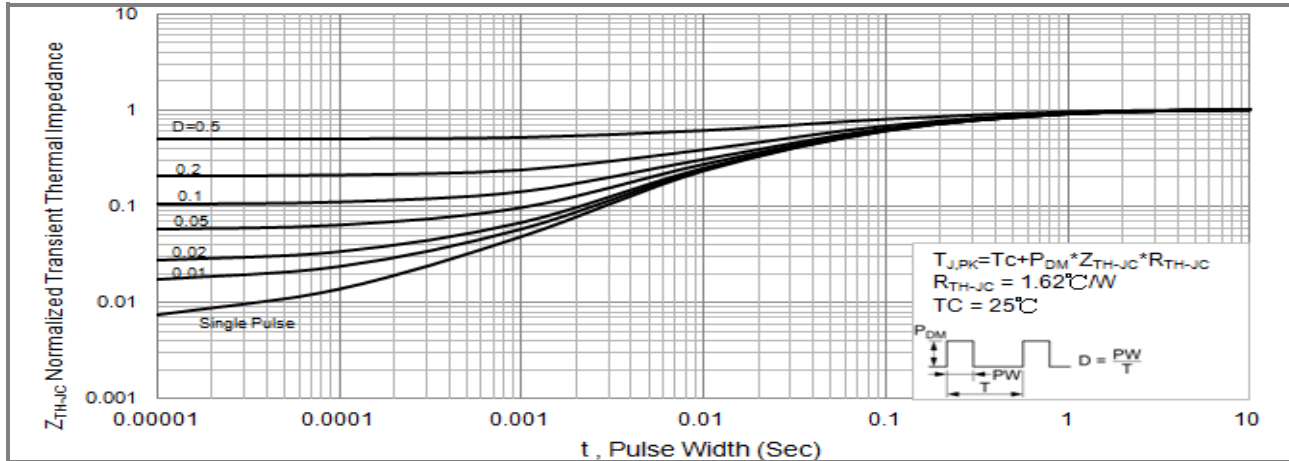


Fig.13 PJU/PJD Normalized Transient Thermal Impedance vs. Pulse Width

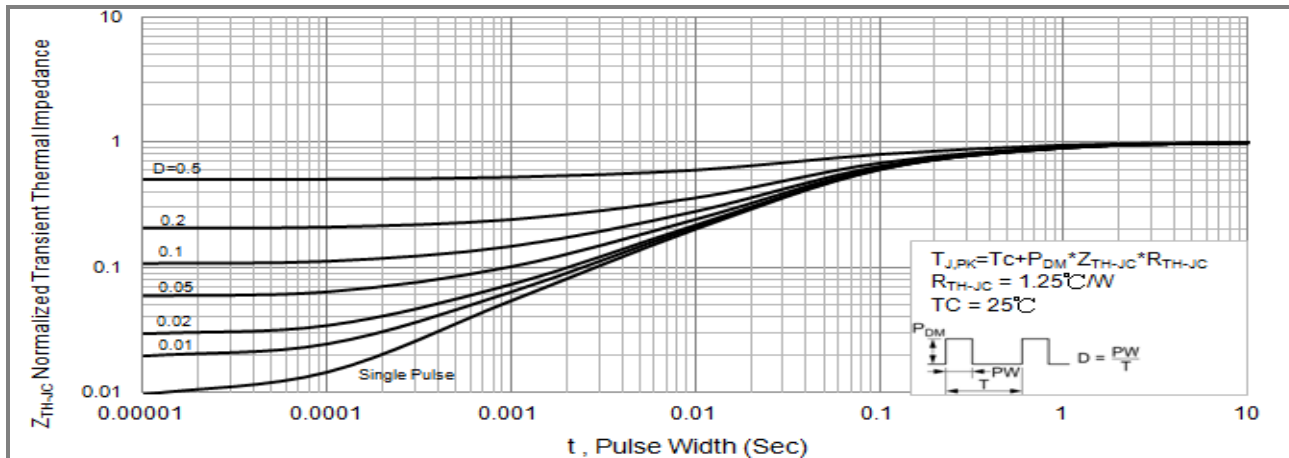


Fig.14 PJP4NA65 Normalized Transient Thermal Impedance vs. Pulse Width

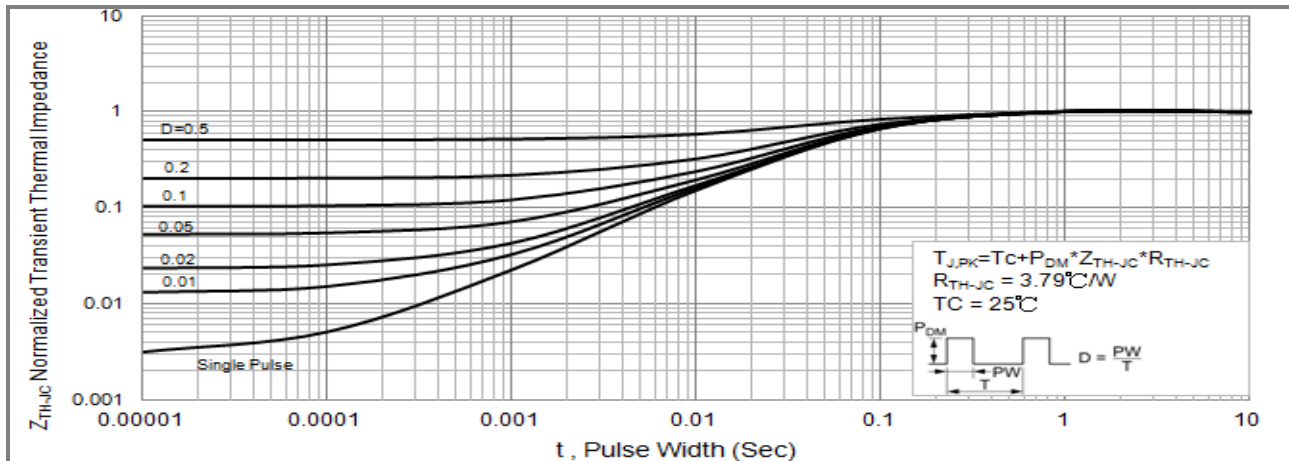
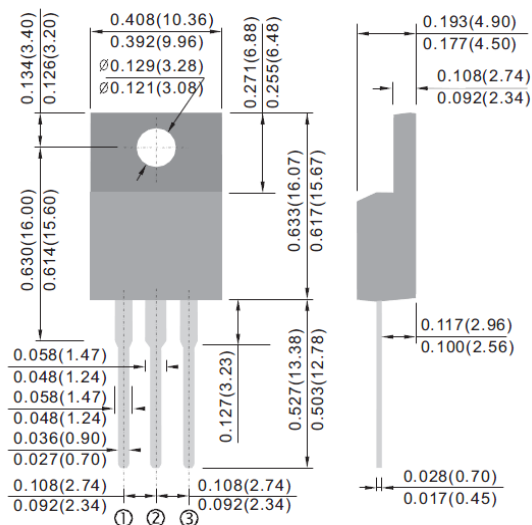


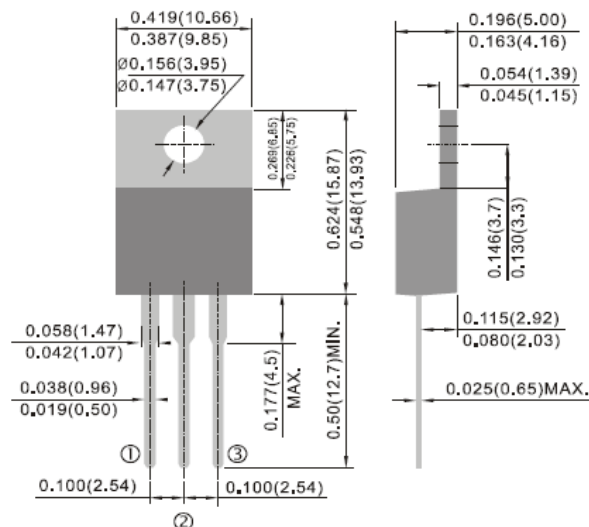
Fig.15 PJF4NA65 Normalized Transient Thermal Impedance vs. Pulse Width

Packaging Information

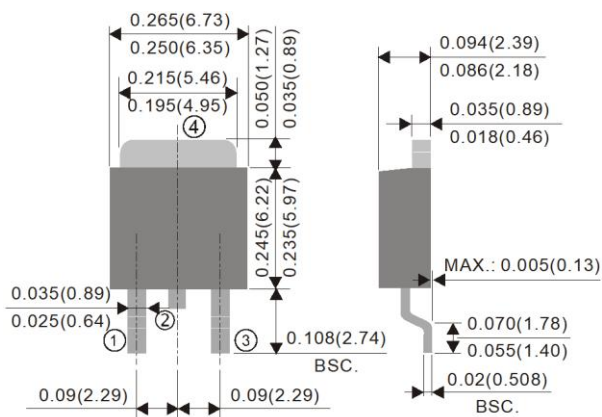
Unit: mm



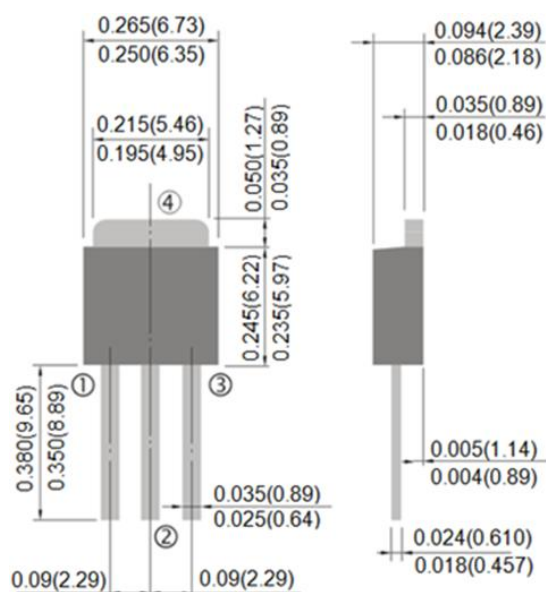
Unit: mm



Unit: mm



Unit: mm





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PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJU4NA65_T0_00001	TO-251AA	80pcs / Tube	U4NA65	Halogen free
PJD4NA65_L2_00001	TO-252AA	3,000pcs / 13" reel	D4NA65	Halogen free
PJP4NA65_T0_00001	TO-220AB	50pcs / Tube	P4NA65	Halogen free
PJF4NA65_T0_00001	ITO-220AB-F	50pcs / Tube	F4NA65	Halogen free



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